NSN 5961-01-511-8662

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-511-8662 **Inclosure Material:** Plastic **Overall Length:** Between 58.10 millimeters and 60.30 millimeters **Overall Height:** Between 1.20 millimeters and 1.30 millimeters **Overall Diameter:** Between 4.80 millimeters and 5.30 millimeters **Mounting Facility Quantity: Mounting Method:** Press fit **Semiconductor Material:** Lead selenide Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 4.00 amperes collector current, dc **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Product Name:** Switchmode power rectifier **Terminal Type And Quantity:** 2 insulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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